

MDV04-600

HIGH VOLTAGE ULTRA-FAST DIODE FOR VIDEO

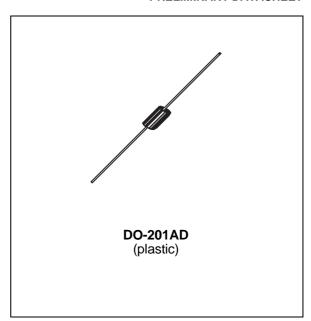
PRELIMINARY DATASHEET

MAJOR PRODUCTS CHARACTERISTICS

| Fpeak | 4 A |
|-------------------------|-------|
| V _{RRM} | 600 V |
| t _{rr} | 55 ns |
| V _F (max) | 1.2 V |

FEATURES AND BENEFITS

- TURBOSWITCH[™] OUTSTANDING BENEFITS.
- HIGH REVERSE VOLTAGE: 600 V
- LOW POWER LOSSES INDUCING LOW TEMPERATURE AND HIGH RELIABILITY.
- OPTIMIZED COMPROMISE BETWEEN t_{rr} AND SOFTNESS FOR VIDEO HORIZONTAL DEFLECTION.



DESCRIPTION

High voltage ultra-fast diode especially designed for modulation and fkyback rectification in standard and figh resolution displays for TV's and monitors.

The device is packaged in a DO-201AD axial enveloppe.

ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | VALUE | Unit | |
|---------------------|--------------------------------------|----------------------|------|---|
| V_{RRM} | Repetitive Peak Reverse Voltage | | 600 | V |
| V_{RWM} | Reverse Working Voltage | | 600 | V |
| I _F peak | Forward Average Current (1) | 4 | Α | |
| | Ambient temperature (2) | 115 | °C | |
| I _{FRM} | Repetitive peak forward current | tp = 5μs f = 1kHz | 100 | Α |
| I _{FSM} | Surge Non Repetitive Forward Current | 150 | Α | |
| T _{stg} | Storage Temperature Range | - 40 to 150 | °C | |
| Tj | Max Operating Junction Temperature | 150 | °C | |

⁽¹⁾ delta = 0.5 and triangular waveform

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⁽²⁾ on infinite heatsink with 10mm lead length

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THERMAL DATA

| Symbol | Parameter | Max. | Unit |
|----------------------|--|------|------|
| R _{th(j-l)} | Junction to lead on infinite heatsink | 21 | °C/W |
| R _{th(j-a)} | Junction to ambient on printed circuit L lead = 10mm | 75 | °C/W |

STATIC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Test Con | ditions | Тур. | Max. | Unit |
|-------------------|-------------------------|----------------------|-------------------------|------|--------------|----------|
| I _R * | Reverse Leakage Current | $V_R = 0.8 V_{RWM}$ | Tj = 25°C Tj = 125°C | | 50 0.75 | μA mA |
| V _F ** | Forward Voltage Drop | I _F = 4 A | Tj = 25°C Tj = 125°C | | 1.28 1.20 | V |

Pulse test:

DYNAMIC ELECTRICAL CHARACTERISTICS

TURN-OFF SWITCHING

| Symbol | Parameter | Test Conditions | Тур. | Max. | Unit |
|-----------------|-----------------------|---|------|------|------|
| t _{rr} | Reverse Recovery Time | I _F = 0.5A I _R = 1A Irr = 0.25A | 55 | 75 | ns |
| | | I _F = + 100 mA / - 100 mA | 130 | | ns |

DYNAMIC ELECTRICAL CHARACTERISTICS

TURN-ON SWITCHING

| Symbol | Parameter | Test Conditions | Тур. | Max. | Unit |
|-----------------|-----------------------|---|------|------|------|
| t _{fr} | Forward Recovery Time | $I_F = 4 \text{ A}$ $dI_F/dt = 100 \text{ A/}\mu\text{s}$ | | 0.5 | μs |
| V _{FP} | Peak Forward Voltage | Measured at V _F max. Tj = 25°C | | 15 | V |

To evaluate the maximum conduction losses use the following equation :

$$P = \frac{1.0 \times I_p}{2} \times \delta + \frac{0.050 \times I_p^{\ \ 2}}{3} \times \delta$$

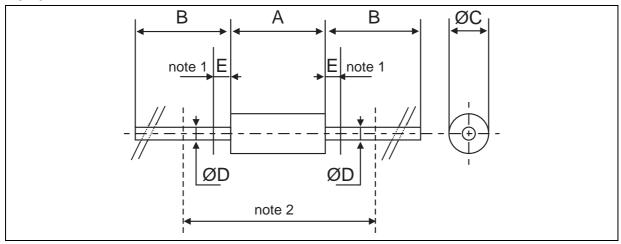
 δ : duty cycle Ip: Peak current

Ex : for $\,\,I_{P}$ = 4 A and δ = 0.5, P = 1.2 Watts.

^{*} tp = 5 ms, duty cycle < 2%** tp = $380 \mu s$, duty cycle < 2%

PACKAGE MECHANICAL DATA

DO-201AD



| | | DIMEN | SIONS | | |
|------|--------|---------------|-------|-------|--|
| REF. | Millin | neters Inches | | hes | NOTES |
| | Min. | Max. | Min. | Max. | |
| Α | | 9.50 | | 0.374 | 1 - The lead diameter Ø D is not controlled over zone E |
| В | 25.40 | | 1.000 | | 2 - The minimum axial lengh within which the device may be |
| ØC | | 5.30 | | 0.209 | placed with its leads bent at right angles is 0.59"(15 mm) |
| ØD | | 1.30 | | 0.051 | |
| Е | | 1.25 | | 0.049 | |

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